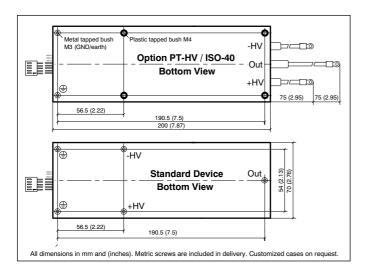
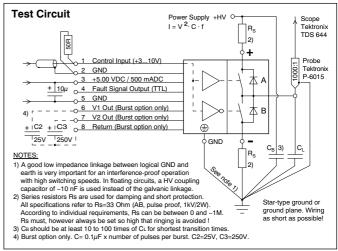
## **FAST HIGH VOLTAGE TRANSISTOR SWITCHES**

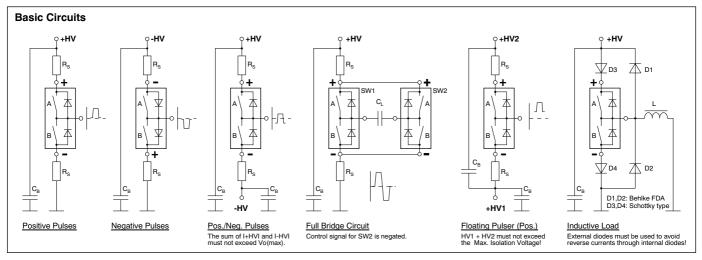
The switching modules of the series HTS-GSM consist of two identical MOSFET switching paths that form a so-called half bridge circuit respectively push-pull circuit. Both switching paths are controlled by a common driver, which also provides a logic signal negation for one of the switches. The switches are mutually passively locked, so that a short in the bridge is excluded under all circumstances, including if the control input is disturbed by electromagnetic interferences (due to bad EMC design, for example). Especially in pulse generator applications with capacitive load, the push-pull principle has considerable advantages in comparision with the conventional circuitry using a single-switch with a working resistor. Push-pull circuits do not require large energy storage capacitors for a low pulse drop and, because there are no working resistor power losses, the efficiency of a push-pull pulser is excellent regardless of pulse width, frequency and duty cycle. The pulsers draw only currents for charging the connected load capacitance. Thanks to an extremely precise timing of the switches, there are also almost no cross currents in the bridge, except peak charging currents of the switch natural capacitances.

The switches are controlled by positive going signals of 3 to 10 Volts amplitude. Fault conditions as overfrequency, thermal overload (long-term overload) and incorrect auxilliary supply set the switching path A in off-state and the switching path B in onstate. Faults are indicated as an "L" signal at the fault signal output. Without 5VDC supply, both switching paths (A and B) are in off-state. That implies, without 5VDC the output potential could be undefined if the HV is still applied. To ensure a defined high voltage output potential in such cases, pull-up or pull-down resistors must be connected to the output. For further design recommendations, please refer to the general instructions.









## **TECHNICAL DATA**

	Specification	Symbol	Condition / Comment					HTS 111-06-GSM	HTS 201-03-GSM	Unit
3.5	Maximum Operating Voltage	V <sub>O(max)</sub>	I <sub>off</sub> <10 μADC, full temperature range, both switching paths, one pole grounded				±11000	± 20000	VDC	
RATING	Maximum Galvanic Isolation Voltage	V <sub>I(max)</sub>	Continuously, between Control circuit and switching paths  HV terminals at bottom (Standard) HV pigtails at front, Option ISO-40 HV pigtails at front, Option ISO-80				± 25000 ± 40000 ± 80000		VDC	
2	Maximum Peak Current 5)	I <sub>P(max)</sub>	T <sub>case</sub> = 25°C t	t <sub>p</sub> < 10 μs, duty cycle <1%				60 30		ADC
MAXIMUM RATINGS	Maximum Continuous Load Current	I <sub>L(max)</sub>	Each switching path T <sub>case</sub> = 25°C	Standard plastic case, (forced Option CF, cooling fins, (forced Option DLC or DLC-ISO (1 litre			ed air >4m/s) 1) itre / min) 2)	0.69 2.67 3.09	0.33 1.29 1.49	ADC
	Maximum Continuous Power Dissipation	P <sub>d(max)</sub>	T <sub>case</sub> = 25°C (	Option CF, cooling fins, (forced air >4m/s) 1) Option DLC or DLC-ISO (1 litre / min) 2)			20 300 400		Watts	
ABSOLUTE	Linear Derating		$T_{case} = 25^{\circ}C$	Standard plastic case, (forced air >4m/s) Option CF, cooling fins, (forced air >4m/s) Option DLC or DLC-ISO (1 litre / min)  2)			ed air >4m/s) 1)	0.44 6.66 8.88		W/K
L	Maximum Auxilliary Voltage	V <sub>aux(max)</sub>	Built-in overvoltage limiter (replaceable)				5.25		VDC	
	Permissible Operating Voltage Range	Vo	Unipolar operation (one switch pole grounded or floated on same polarity) Bipolar operation (positive & negative voltages symmetrically applied)			0 ± 11000 0 ± 5500	0 ± 20000 0 ± 10000	VDC		
	Typical Breakdown Voltage	V <sub>br</sub>	loff > 1 mADC, T <sub>case</sub> =70 °C. Parameter is for quality testing purposes only!				± 13000	± 25000	VDC	
	Maximum Off-State Current	loff	0.8 x V <sub>0</sub> , T <sub>case</sub> = 2570°C, reduced l <sub>off</sub> on request					10		μADC
CHARACTERISTICS	Typical Static On-Resistance	R <sub>stat</sub>	Each switching path T <sub>case</sub> = 25°C	25°C		0.8 x I <sub>P(max)</sub> 1.0 x I <sub>P(max)</sub>		10 21	43 90	Ω
	Typical Capacitive Power Dissipation of Switch (Natural Power Dissipation)	P <sub>dc</sub>	Switch capacitances only – without external load and parasitic capacitances! The total capacitive power dissipation is determined by the equation $P_{dc(tot)} = V^2 \times C_{tot} \times f$			0.8 x V <sub>O(max</sub> 0.8 x V <sub>O(max</sub>		0.046 0.46 4.6 46	0.154 1.54 15.4 154	Watts
	Typical Output Transition Time (Rise Time & Fall Time)	t <sub>r</sub> , t <sub>f</sub>	Standard device 0.8 x V <sub>0</sub> 10-90%			R <sub>S</sub> =33Ω, C <sub>L</sub> = 10pF R <sub>S</sub> =33Ω, C <sub>L</sub> = 50pF R <sub>S</sub> =33Ω, C <sub>L</sub> = 100pF R <sub>S</sub> =33Ω, C <sub>L</sub> = 200pF R <sub>S</sub> =22Ω, C <sub>L</sub> =1000pF		7 9 12 19 55	14 18 26 45 80	
	Drangation Daloy Time	td	Option S-1			Option S-TT,	R <sub>S</sub> =33Ω, C <sub>L</sub> =10pF	30	35	ns
15	Propagation Delay Time Minimum Output Pulse Width			ve load, shorter delay available on request				150 150		ns
3	Maximum Output Pulse Width	t <sub>p(min)</sub>	Reduced minimum output pulse width available on request  No limitation						ns	
4		t <sub>p(max)</sub>						∞ 300		S
H	Minimum Pulse Spacing Typical Output Pulse Jitter	tps(min)	(Switch recovery time) V <sub>aux</sub> =5.0 VDC Fixed switching frequency, >2kHz				auanay SakHz	0.1		ns
	i ypicai Output Puise Jittei	tj	V <sub>tr</sub> =5.0 VDC	Sweeped frequency, <2kHz				2		ne
ECTRICAL	Maximum Continuous Switching Frequency 3)	f <sub>(max)</sub>	T <sub>case</sub> = 25°C High switching frequencies requi	Standard es require Option F				1	5 00	ns
EC		_	sufficient cooling methods! Options HFS+DLC or CF-			or CF+CF-DR		00	kHz	
ELI	Maximum Burst Frequency	f <sub>b(max)</sub>	Use option HFB for >10 pulses within 20µs or less				3.3		MHz	
	Operating Temperature Range	T <sub>0</sub>	Extended temperature range on	ded temperature range on request				- 40 70		°C
	Storage Temperature Range	Tst	Consider the second state with the second se				- 50100		°C	
	Typical Natural Capacitance of Switch	C <sub>N</sub>	0.8 x V <sub>O(max)</sub>				0.1 x V <sub>O(max)</sub> 0.8 x V <sub>O(max)</sub>	< 90 < 30		pF
	Typical Coupling Capacitance	Cc	Both switches against ground, respectively, control circuit				<	30	pF	
	of Intrinsic Diodes	trrc	Repetitive forward current through the diodes (current reversal) may damage the switch. Please refer to note 4) $I_F = 2A$				<1		μs	
	Auxiliary Supply Voltage Range	V <sub>aux</sub>	5.00 V ± 2% recommended					4.75 5.25		VDC
	Auxiliary Supply Current	l <sub>aux</sub>	(1000 mA current limitation recommended) $f < 500 \text{ Hz}$ f = 5  kHz				< 400 < 700		mADC	
	Control Signal	V <sub>tr</sub>	>3VDC recommended for low jitter				310		VDC	
	Fault Signal Output		Switch will be turned off, if $f > f_{(max)}$ , $V_{aux} < 4.75V$ or $T_{case} > 75^{\circ}C$ Ready = "H" Fault condition is indicated by a logical "L" Fault = "L"				≥4.0 ≤0.8		VDC	
75	Dimensions	LxWxH	Standard plastic case (HV terminals at bottom) Option DLC or DLC-ISO (HV terminals on top)				200 x 70 x 28 200 x 70 x 35		,,,,,	
GENERAL	Weight		Option CF (HV terminals at bottom) Standard plastic case				200 x 70 x 89 < 750g		mm <sup>3</sup>	
GE	···oigiit		Option DLC or DLC-ISO Option CF					< 9	900g 100g	g

- 1) Switches with cooling fins can also be immersed in non-conductive cooling liquids (e.g. GALDEN). Depending on the liquid characteristics, flow rate and temperature, a P<sub>d(max)</sub> of up to 1200 Watts can be achieved with standard cooling fins. 2) The specifications for option DLC and DLC-ISO refer to the standard housing dimensions. Customized liquid cooling options for up to 3000 Watts power dissipation are available in larger housings. Please consult factory.
- 3) The  $f_{(max)}$  parameter specifies the driver capability only. The maximum switching frequency of switch is limited by  $P_{d(max)}$  restrictions, depending on the individual switch configuration & cooling option. Please consult factory.

  4) The intrinsic diodes must not be used in normal operation. High stray inductancies or inductive load requires a fast free-wheeling diode network (series & parallel diode) or sufficient damping resistors in series to the HV inputs.

  5) Current limiting resistors are not required at moderate capacitive load  $(C_L < 10 \text{ nF})$ . Nevertheless, series resistors  $(R_S)$ , in the order of 10 to 100  $\Omega$ , may be required for damping purposes (avoidance of pulse overshoot & undershoot).

## Ordering Information

HTS 111-06-GSM HTS 201-03-GSM Option HFB Option HFS Option S-TT Option SPT-C

11kV Push-pull transistor switch 20kV Push-pull transistor switch High frequency burst High frequency switching Soft Transition Time Shielded input cable with LEMO plug Option CF Option GCF Option DLC Option DLC-ISO Option ISO-40 Option ISO-80

Cooling fins, non isolated. Fins must not be shortet or grounded Grounded cooling flange for heat sink assembly.  $R_{\text{th}} < 0.15 \text{ K/W}$ Direct liquid cooling for non-conductive liquids (e.g. GALDEN) Direct liquid cooling for conductive liquids (e.g. mains water) 40kV isolation, HV pigtails on the front side of housing 80kV isolation, HV pigtails on the front side, enlarged housing

For further options, please refer to survey C8 of catalog. Detailed data and mechanical drawings are available on request. All data and specifications subject to change without notice.

Datasheet HTS 201-03-GSM Revision 12-04-2009